

# High-side Power Switch with Diagnostic Function SI-5155S

## Features

- Built-in diagnostic function to detect short and open circuiting of loads and output status signals
- Low saturation PNP transistor use
- Allows direct driving using LS-TTL and C-MOS logic levels
- Built-in overcurrent and thermal protection circuits
- Built-in protection against reverse connection of power supply
- $T_j = 150^\circ\text{C}$  guaranteed
- TO-220 equivalent full-mold package not require insulation mica

## Absolute Maximum Ratings

( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Ratings	Unit	Conditions
Power supply voltage	$V_B$	-13 to +40	V	
Input terminal voltage	$V_{IN}$	-0.3 to $V_B$	V	
DIAG terminal voltage	$V_{DIAG}$	6	V	
Collector-emitter voltage	$V_{CE}$	40	V	
Output current	$I_O$	2.5	A	
Power dissipation	$P_{D1}$	22	W	With infinite heatsink ( $T_c = 25^\circ\text{C}$ )
	$P_{D2}$	1.8	W	Stand-alone without heatsink
Junction temperature	$T_j$	-40 to +150	°C	
Operating temperature	$T_{OP}$	-40 to +100	°C	
Storage temperature	$T_{STG}$	-40 to +150	°C	

## Electrical Characteristics

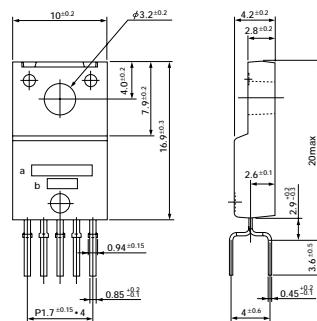
( $T_a = 25^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Ratings			Unit	Conditions
		min	typ	max		
Operating power supply voltage	$V_{Bopr}$	6.0		30	V	
Quiescent circuit current	$I_Q$		5	12	mA	$V_{Bopr} = 14V, V_{IN} = 0V$
Saturation voltage of output transistor	$V_{CE(\text{sat})}$			0.3	V	$I_O \leq 1.0A, V_{Bopr} = 6$ to 16V
				0.72	V	$I_O \leq 2.5A, V_{Bopr} = 6$ to 16V
Output leak current	$I_{O, \text{leak}}$			2	mA	$V_{CEO} = 16V, V_{IN} = 0V$
Input voltage	Output ON	$V_{IH}$	2.0		V	$V_{Bopr} = 6$ to 16V
	Output OFF	$V_{IL}$	-0.3		V	$V_{Bopr} = 6$ to 16V
Input current	Output ON	$I_{IH}$		1	mA	$V_{IN} = 5V$
	Output OFF	$I_{IL}$	-0.1		mA	$V_{IN} = 0V$
Overcurrent protection starting current	$I_S$	2.6			A	$V_{Bopr} = 14V, V_O = V_{Bopr} - 1.5V$
Thermal protection starting temperature	$T_{TSD}$	150			°C	$V_{Bopr} \geq 6V$
Open load detection resistor	$R_{open}$			30	kΩ	$V_{Bopr} = 6$ to 16V
Output transfer time	$T_{ON}$		8	30	μS	$V_{Bopr} = 14V, I_O = 1A$
	$T_{OFF}$		15	30	μS	$V_{Bopr} = 14V, I_O = 1A$
DIAG output voltage	$V_{DH}$	4.5		6	V	$V_{CC} = 6V, V_{Bopr} = 6$ to 16V
	$V_{DL}$			0.3	V	$V_{CC} = 6V, V_{Bopr} = 6$ to 16V, $I_{DO} = 2mA$
DIAG output transfer time	$T_{PLH}$			30	μS	$V_{Bopr} = 14V, I_O = 1A$
	$T_{PHL}$			30	μS	$V_{Bopr} = 14V, I_O = 1A$
Minimum load inductance	L	1			mH	

### Note:

\* The rule of protection against reverse connection of power supply is  $V_B = -13V$ , one minute (all terminals except,  $V_B$  and GND, are open).

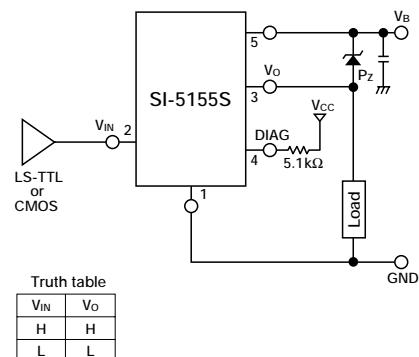
## External Dimensions (unit: mm)



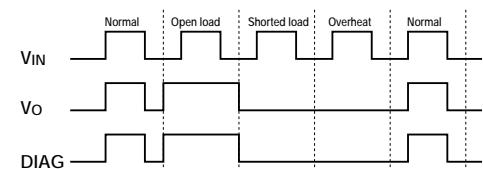
1. GND  
2.  $V_{IN}$   
3.  $V_O$   
4. DIAG  
5.  $V_B$

(Forming No. 1111)

## Standard Circuit Diagram



## Diagnostic Function



Mode	$V_{IN}$	$V_O$	DIAG
Normal	L	L	L
Open load	H	H	H
Shorted load	L	L	L
Overheat	L	L	L

● DIAG output will be undetermined when a voltage exceeding 25V is applied to  $V_B$  terminal.

